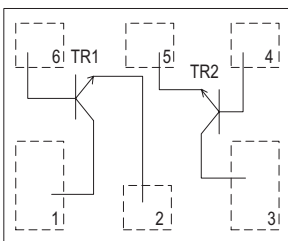
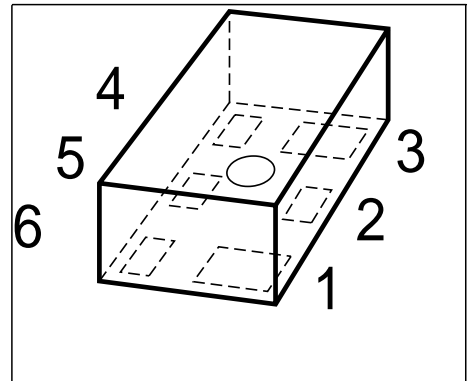


NPN Silicon RF TWIN Transistor

Preliminary data

- Low voltage/ low current applications
- Ideal for VCO modules and low noise amplifiers
- Low noise figure: TR1: 1.1dB at 1.8 GHz
TR2: 1.5 dB at 1.8 GHz
- World's smallest SMD 6-pin leadless package
- Built in 2 transistors (TR1: die as BFR460L3,
TR2: die as BFR949L3)


ESD: Electrostatic discharge sensitive device, observe handling precaution!

| Type | Marking | Pin Configuration | | | | | | Package |
|----------|---------|-------------------|------|------|------|------|------|----------|
| BFS469L6 | AD | 1=C1 | 2=E1 | 3=C2 | 4=B2 | 5=E2 | 6=B1 | TSLP-6-1 |

Maximum Ratings

| Parameter | Symbol | Value | Unit |
|---------------------------|-----------|-------|------|
| Collector-emitter voltage | V_{CEO} | | V |
| TR1 | | 4.5 | |
| TR2 | | 10 | |
| Collector-emitter voltage | V_{CES} | | |
| TR1 | | 15 | |
| TR2 | | 20 | |
| Collector-base voltage | V_{CBO} | | |
| TR1 | | 15 | |
| TR2 | | 20 | |
| Emitter-base voltage | V_{EBO} | | |
| TR1 | | 1.5 | |
| TR2 | | 1.5 | |
| Collector current | I_C | | mA |
| TR1 | | 50 | |
| TR2 | | 70 | |

Maximum Ratings

| Parameter | Symbol | Value | Unit |
|---------------------------------------|-----------|-------------|------------------|
| Base current | I_B | | mA |
| TR1 | | 5 | |
| TR2 | | 7 | |
| Total power dissipation ¹⁾ | P_{tot} | | mW |
| TR1, $T_S \leq 104^\circ\text{C}$ | | 200 | |
| TR2, $T_S \leq 100^\circ\text{C}$ | | 250 | |
| Junction temperature | T_j | | $^\circ\text{C}$ |
| TR1 | | 150 | |
| TR2 | | 150 | |
| Ambient temperature | T_A | | |
| TR1 | | -65 ... 150 | |
| TR2 | | -65 ... 150 | |
| Storage temperature | T_{stg} | | |
| TR1 | | -65 ... 150 | |
| TR2 | | -65 ... 150 | |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
|--|------------|------------|------|
| Junction - soldering point ²⁾ | R_{thJS} | | K/W |
| TR1 | | ≤ 230 | |
| TR2 | | ≤ 200 | |

¹⁾ T_S is measured on the collector lead at the soldering point to the pcb

²⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Values | | | Unit |
|--|---------------|-----------|------------|------------|---------------|
| | | min. | typ. | max. | |
| DC Characteristics | | | | | |
| Collector-emitter breakdown voltage TR1, $I_C = 1\text{ mA}$, $I_B = 0$ TR2, $I_C = 1\text{ mA}$, $I_B = 0$ | $V_{(BR)CEO}$ | 4.5 10 | 5 - | - - | V |
| Collector-emitter cutoff current TR1, $V_{CE} = 15\text{ V}$, $V_{BE} = 0$ TR1, $V_{CE} = 20\text{ V}$, $V_{BE} = 0$ | I_{CES} | - - | - - | 10 10 | μA |
| Collector-base cutoff current TR1, $V_{CB} = 5\text{ V}$, $I_E = 0$ TR2, $V_{CB} = 10\text{ V}$, $I_E = 0$ | I_{CBO} | - - | - - | 100 100 | nA |
| Emitter-base cutoff current TR1, $V_{EB} = 0,5\text{ V}$, $I_C = 0$ TR2, $V_{EB} = 1\text{ V}$, $I_C = 0$ | I_{EBO} | - - | - - | 1 0.1 | μA |
| DC current gain- TR1, $I_C = 20\text{ mA}$, $V_{CE} = 3\text{ V}$ TR2, $I_C = 5\text{ mA}$, $V_{CE} = 3\text{ V}$ | h_{FE} | - 100 | 130 140 | - 200 | - |

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Values | | | Unit |
|--|----------|-----------|--------------|-------------|------|
| | | min. | typ. | max. | |
| AC Characteristics (verified by random sampling) | | | | | |
| Transition frequency TR1, $I_C = 30\text{ mA}$, $V_{CE} = 3\text{ V}$, $f = 1\text{ GHz}$ TR2, $I_C = 15\text{ mA}$, $V_{CE} = 6\text{ V}$, $f = 1\text{ GHz}$ | f_T | 16 tbd | 22 9 | - - | GHz |
| Collector-base capacitance TR1, $V_{CB} = 3\text{ V}$, $f = 1\text{ MHz}$, emitter grounded TR2, $V_{CB} = 10\text{ V}$, $f = 1\text{ MHz}$, emitter grounded | C_{cb} | - - | 0.33 0.3 | 0.5 0.45 | pF |
| Collector emitter capacitance TR1, $V_{CE} = 3\text{ V}$, $f = 1\text{ MHz}$, base grounded TR1, $V_{CE} = 10\text{ V}$, $f = 1\text{ MHz}$, base grounded | C_{ce} | - - | 0.17 0.17 | - - | |
| Emitter-base capacitance TR1, $V_{EB} = 0,5\text{ V}$, $f = 1\text{ MHz}$, collector grounded TR2, $V_{EB} = 0,5\text{ V}$, $f = 1\text{ MHz}$, collector grounded | C_{eb} | - - | 0.57 0.75 | - - | |

Electrical Characteristics at TA = 25°C, unless otherwise specified

| Parameter | Symbol | Values | | | Unit |
|---|-------------------|--------|------|------|------|
| | | min. | typ. | max. | |
| AC Characteristics (verified by random sampling) | | | | | |
| Noise figure | F | | | | dB |
| TR1, $I_C=5\text{mA}$, $V_{CE} = 3\text{ V}$, $f = 1.8\text{ GHz}$, $Z_S = Z_{\text{Sopt}}$ | | - | 1.1 | - | |
| TR1, $I_C=5\text{mA}$, $V_{CE} = 3\text{ V}$, $f = 3\text{ GHz}$, $Z_S = Z_{\text{Sopt}}$ | | - | 1.4 | - | |
| TR2, $I_C=3\text{mA}$, $V_{CE} = 6\text{ V}$, $f = 1\text{ GHz}$, $Z_S = Z_{\text{Sopt}}$ | | - | 1 | - | |
| TR2, $I_C=3\text{mA}$, $V_{CE} = 8\text{ V}$, $f = 1.8\text{ GHz}$, $Z_S = Z_{\text{Sopt}}$ | | - | 1.3 | - | |
| Power gain, maximum stable ¹⁾ | G_{ms} | | | | |
| TR1, $I_C = 20\text{ mA}$, $V_{CE} = 3\text{ V}$, $Z_S=Z_{\text{Sopt}}$, $Z_L=Z_{\text{Lopt}}$, $f = 1.8\text{ GHz}$ | | - | 14.5 | - | |
| TR2, $I_C = 10\text{ mA}$, $V_{CE} = 8\text{ V}$, $Z_S=Z_{\text{Sopt}}$, $Z_L=Z_{\text{Lopt}}$, $f = 0.9\text{ GHz}$ | | - | 20 | - | |
| TR2, $I_C = 10\text{ mA}$, $V_{CE} = 8\text{ V}$, $Z_S=Z_{\text{Sopt}}$, $Z_L=Z_{\text{Lopt}}$, $f = 1.8\text{ GHz}$ | | - | 14 | - | |
| Power gain, maximum available ¹⁾ | G_{ma} | - | 10 | - | |
| TR1, $I_C = 20\text{mA}$, $V_{CE} = 3\text{ V}$, $Z_S = Z_{\text{Sopt}}$, $Z_L = Z_{\text{Lopt}}$, $f = 1.8\text{ GHz}$ | | | | | |
| Transducer gain | $ S_{21e} ^2$ | | | | |
| TR1, $I_C=20\text{mA}$, $V_{CE} = 3\text{ V}$, $Z_S=Z_L=50\Omega$, $f=1.8\text{GHz}$ | | - | 12.5 | - | |
| TR1, $I_C=20\text{mA}$, $V_{CE} = 3\text{ V}$, $Z_S=Z_L=50\Omega$, $f=3\text{GHz}$ | | - | 9 | - | |
| TR2, $I_C=15\text{mA}$, $V_{CE} = 6\text{ V}$, $Z_S=Z_L=50\Omega$, $f=1\text{GHz}$ | | - | 15,5 | - | |
| TR2, $I_C=10\text{mA}$, $V_{CE} = 8\text{ V}$, $Z_S=Z_L=50\Omega$, $f=1.8\text{GHz}$ | | - | 11 | - | |
| Third order intercept point at output ²⁾ | IP_3 | | | | dBm |
| TR1, $V_{CE}=3\text{V}$, $I_C=20\text{mA}$, $Z_S=Z_L=50\Omega$, $f=1.8\text{GHz}$ | | - | 28 | - | |
| TR2, $V_{CE}=8\text{V}$, $I_C=10\text{mA}$, $Z_S=Z_L=50\Omega$, $f=1.8\text{GHz}$ | | - | 24.5 | - | |
| 1dB Compression point at output | $P_{-1\text{dB}}$ | | | | |
| TR1, $I_C=20\text{mA}$, $V_{CE}=3\text{V}$, $Z_S=Z_L=50\Omega$, $f=1.8\text{GHz}$ | | - | 12 | - | |
| TR1, $I_C=10\text{mA}$, $V_{CE}=8\text{V}$, $Z_S=Z_L=50\Omega$, $f=1.8\text{GHz}$ | | - | 6 | - | |

$$^1G_{\text{ma}} = |S_{21e} / S_{12e}| (k - (k^2 - 1)^{1/2}), G_{\text{ms}} = |S_{21e} / S_{12e}|$$

²IP3 value depends on termination of all intermodulation frequency components.

Termination used for this measurement is 50Ω from 0.1 MHz to 6 GHz

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